

CAN transceiver for 24 V systems

■ Description

The TK82C251 is the interface between a CAN protocol controller and the physical bus. The device provides differential transmit capability to the bus and differential receive capability to the CAN controller. A current-limiting circuit protects the transmitter output stage against short-circuits to positive and negative battery voltage. Although power dissipation will increase as a result of a short circuit fault condition, this feature will prevent destruction of the transmitter output stage.

If the junction temperature exceeds approximately 160°C, the limiting current of both transmitter outputs is decreased. Because the transmitter is responsible for most of the power dissipated, this will result in reduced power dissipation and hence a lower chip temperature. All other parts of the IC will remain operational. The thermal protection is needed, in particular, when a bus line is short-circuited.

The CANH and CANL lines are also protected against electrical transients which may occur in an automotive environment.

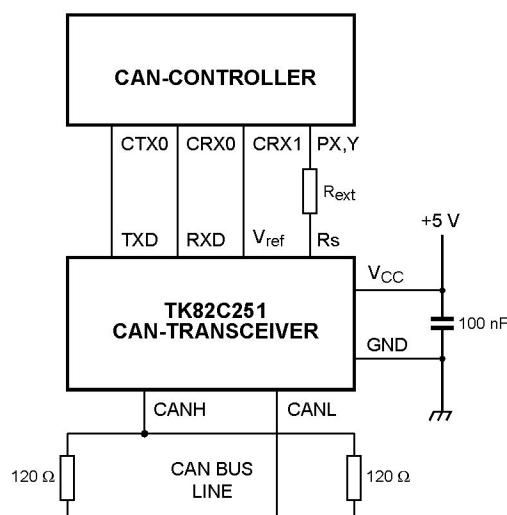
Pin 8 (Rs) allows three different modes of operation to be selected: High-speed, Slope control and Standby. For high-speed operation, the transmitter output transistors are simply switched on and off as fast as possible. In this mode, no measures are taken to limit the rise and fall slopes. A shielded cable is recommended to avoid RFI problems. High-speed mode is selected by connecting pin 8 to ground.

■ Features

- An unpowered node does not disturb the bus lines
- Slope control to reduce Radio Frequency Interference (RFI)
- High speed (up to 1 MBd)
- High immunity against electromagnetic interference.
- Low-current Standby mode
- Fully compatible with the "ISO 11898-24 V" standard
- At least 110 nodes can be connected
- Short-circuit proof to battery and ground in 24 V powered systems

■ Applications

- High-speed applications (up to 1 MBd) in trucks and busses.



Notes:

- (1) The output control register of the P8xC592 should be programmed to 1AH (push-pull operation, dominant = LOW).
- (2) If no slope control is desired: R_{ext} = 0

Fig1

TK82C251 CAN transceiver application diagram

■ Ordering Information

Part Number	Package	Packing	Operating Temperature	Package Qty	
TK82C251TR	SOIC-8	Reel	-20°C ~ 105°C	2500	

■ Pin Assignment

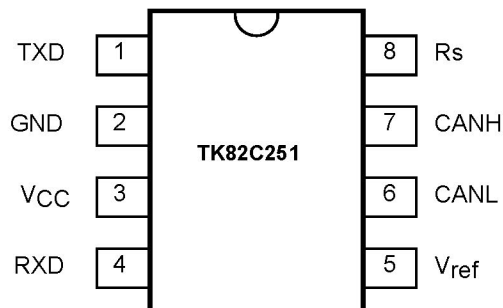


Fig2. SOIC-8 Package

■ Pin Description

Symbol	Pin	Description
TXD	1	transmit data input
GND	2	ground
V _{CC}	3	supply voltage
RXD	4	receive data output
V _{ref}	5	reference voltage output
CANL	6	LOW-level CAN voltage input/output
CANH	7	HIGH-level CAN voltage input/output
Rs	8	slope resistor input

■ ABSOLUTE MAXIMUM RATINGS

Supply Voltage	$0.3\text{ V} \leq V_{CC} \leq +7.0\text{ V}$	Electrostatic discharge voltage	$2500 \leq V_{ESD} \leq +2500\text{ V}$
DC voltage at pins 1, 4, 5 and 8	$-0.3 \leq V_n \leq +0.3\text{ V}$	Storage temperature	$-55 \leq T_{stg} \leq +150^\circ\text{C}$
DC voltage at pin 6 (CANL)	$-36 \leq V_6 \leq +36\text{ V}$	Temperature Range	$-20^\circ\text{C} \leq T_A \leq 105^\circ\text{C}$
DC voltage at pins 7 (CANH)	$-36 \leq V_7 \leq +36\text{ V}$	Supply Temperature	-65°C to $+150^\circ\text{C}$
Transient voltage at pins 6 and 7	$-200 \leq V_6 \leq +200\text{ V}$		

* Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

■ ELECTRICAL CHARACTERISTICS

$V_{CC} = 4.5\text{ V}$ to 5.5 V ; $T_{amb} = -40^\circ\text{C}$ to $+125^\circ\text{C}$; $R_L = 60\ \Omega$; $I_B > -10\ \mu\text{A}$; unless otherwise specified; all voltages referenced to ground (pin 2); positive input current; all parameters are guaranteed over the ambient temperature range by design, but only 100 % tested at $+25^\circ\text{C}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Supply							
I ₃	supply current	dominant; V ₁ = 1 V; V _{CC} = 5.1 V	-	-	78	mA	
		dominant; V ₁ = 1 V; V _{CC} = 5.25 V	-	-	80	mA	
		dominant; V ₁ = 1 V; V _{CC} = 5.5 V	-	-	85	mA	
		recessive; V ₁ = 4 V; R ₈ = 47 kΩ	-	-	10	mA	
		Standby	[1]	-	-	275	μA
DC bus transmitter							
V _{IH}	HIGH-level input voltage	output recessive	0.7V _{CC}	-	V _{CC} + 0.3	V	
V _{IL}	LOW-level input voltage	output dominant	-0.3	-	0.3V _{CC}	V	
I _{IH}	HIGH-level input current	V ₁ = 4 V	-200	-	+30	μA	
I _{IL}	LOW-level input current	V ₁ = 1 V	-100	-	-600	μA	
V _{6,7}	recessive bus voltage	V ₁ = 4 V; no load	2.0	-	3.0	V	
I _{LO}	off-state output leakage current	-2 V < (V ₆ , V ₇) < 7 V	-2	-	+2	mA	
		-5 V < (V ₆ , V ₇) < 36 V	-10	-	+10	mA	
V ₇	CANH output voltage	V ₁ = 1 V; V _{CC} = 4.75 V to 5.5 V	3.0	-	4.5	V	
		V ₁ = 1 V; V _{CC} = 4.5 V to 4.75 V	2.75		4.5		
V ₆	CANL output voltage	V ₁ = 1 V	0.5	-	2.0	V	
ΔV _{6, 7}	difference between output voltage at pins 6 and 7	V ₁ = 1 V	1.5	-	3.0	V	
		V ₁ = 1 V; R _L = 45 Ω	1.5	-	-	V	
		V ₁ = 4 V; no load	-500	-	+50	mV	
I _{sc7}	short-circuit CANH current	V ₇ = -5 V	-	-	-200	mA	
		V ₇ = -36 V	-	-100	-	mA	
I _{sc6}	short-circuit CANL current	V ₆ = 36 V	-	-	200	mA	
DC bus receiver: V ₁ = 4 V; pins 6 and 7 externally driven; -2 V < (V ₆ , V ₇) < 7 V; unless otherwise specified							
V _{diff(r)}	differential input voltage (recessive)		[2]	-1.0	-	+0.5	V
		-7 V < (V ₆ , V ₇) < 12 V	[2]	-1.0	-	+0.4	V

■ ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{diff(d)}	differential input voltage (dominant)		0.9	-	5.0	V
		-7 V < (V ₆ , V ₇) < 12 V; not Standby mode	1.0	-	5.0	V
		Standby mode	0.97	-	5.0	V
		Standby mode; V _{CC} = 4.5 V to 5.10 V	0.91	-	5.0	V
		see Fig 5	-	150	-	mV
V _{OH}	HIGH-level output voltage	pin 4; I ₄ = -100 μA	0.8V _{CC}	-	V _{CC}	V
V _{OL}	LOW-level output voltage	pin 4; I ₄ = 1 mA	0	-	0.2V _{CC}	V
		I ₄ = 10 mA	0	-	1.5	V
R _i	input resistance	CANH, CANL	5	-	25	kΩ
R _{diff}	differential input resistance		20	-	100	kΩ
Reference output						
V _{ref}	reference output voltage	V ₈ = 1 V; I ₅ < 50 μA	0.45V _{CC}	-	0.55V _{CC}	V
		V ₈ = 4 V; I ₅ < 5 μA	0.4V _{CC}	-	0.6V _{CC}	V
Timing (C _L = 100 pF; see Fig3 , Fig 4 , Fig 6 and Fig 7)						
t _{bit}	minimum bit time	R _{ext} = 0 Ω	-	-	1	μs
t _{onTXD}	delay TXD to bus active	R _{ext} = 0 Ω	-	-	50	ns
t _{offTXD}	delay TXD to bus inactive	R _{ext} = 0 Ω	-	40	80	ns
t _{onRXD}	delay TXD to receiver active	R _{ext} = 0 Ω	-	55	120	ns
t _{offRXD}	delay TXD to receiver inactive	R _{ext} = 0 Ω; T _{amb} < +85 °C V _{CC} = 4.5 V to 5.1 V	-	80	150	ns
		R _{ext} = 0 Ω; V _{CC} = 4.5 V to 5.1 V	-	80	170	ns
		R _{ext} = 0 Ω; T _{amb} < +85 °C	-	90	170	ns
		R _{ext} = 0 kΩ	-	90	190	ns
		R _{ext} = 47 kΩ	-	290	400	ns
t _{onRXD}	delay TXD to receiver active	R _{ext} = 47 kΩ	-	440	550	ns
SR	CANH, CANL slew rate	R _{ext} = 47 kΩ	-	7	-	V/μs
t _{WAKE}	wake-up time from Standby (via pin 8)	see Fig 6	-	-	20	μs
t _{dRXDL}	bus dominant to RXD LOW	V ₈ = 4 V; see Fig 7	-	-	3	μs
Standby/Slope control (pin 8)						
V _{stb}	input voltage for Standby mode		0.75V _{CC}	-	-	V
I _{slope}	Slope control mode current		-10	-	-200	μA
V _{slope}	Slope control mode voltage		0.4V _{CC}	-	0.6V _{CC}	V

[1] $I_1 = I_4 = I_5 = 0\text{ mA}$; $0\text{ V} < V_6 < V_{\text{CC}}$; $0\text{ V} < V_7 < V_{\text{CC}}$; $V_8 = V_{\text{CC}}$; $T_{\text{amb}} < 90\text{ }^\circ\text{C}$.

[2] This is valid for the receiver in all modes: High-speed, Slope control and Standby.

■ THERMAL CHARACTERISTICS

Symbol	Parameter	Conditions	Typ	Unit
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	160	K/W

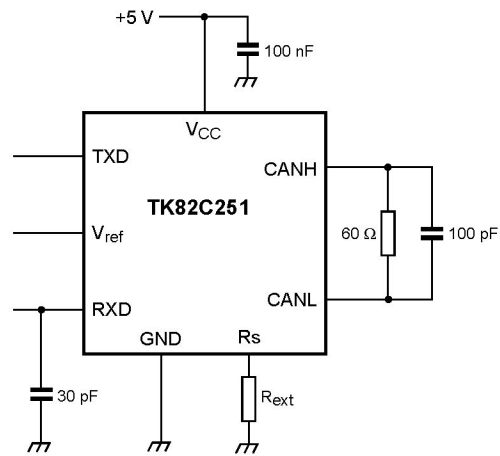


Fig 3. Test circuit for dynamic characteristics.

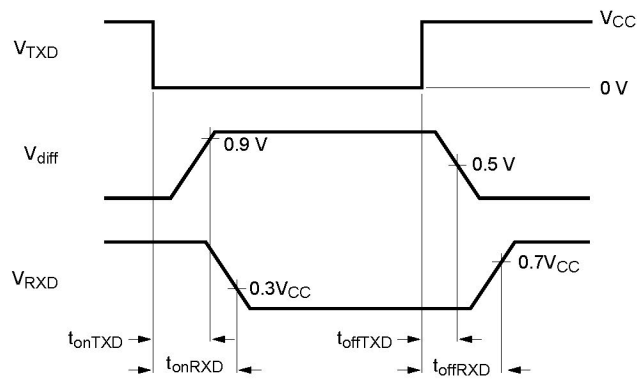


Fig 4. Timing diagram for dynamic characteristics.

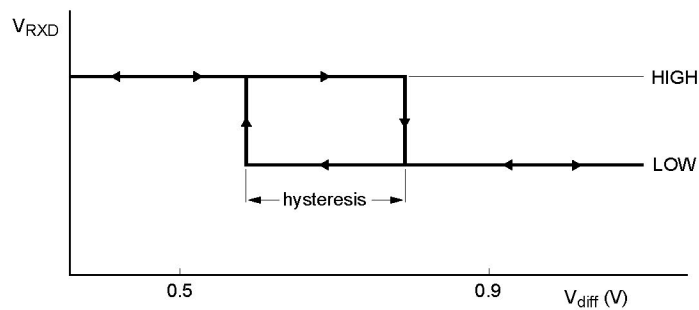
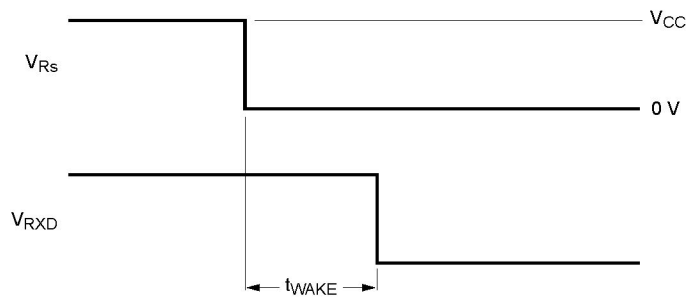
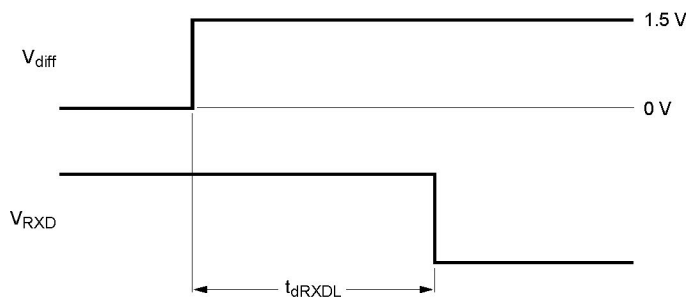


Fig 5. Hysteresis.



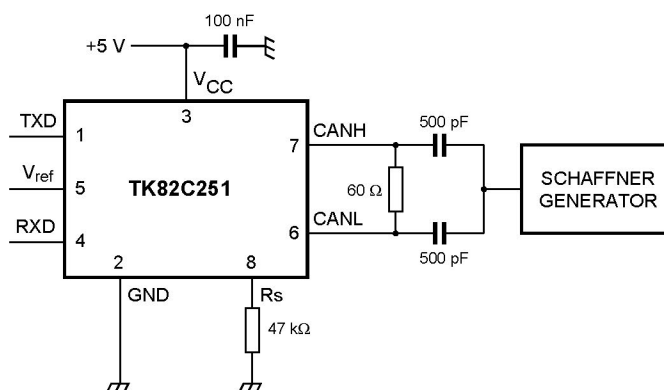
$V_{TXD} = 1\text{ V}$.

Fig 6. Timing diagram for wake-up from Standby.



$V_{Rs} = 4\text{ V}$; $V_{TXD} = 4\text{ V}$.

Fig 7. Timing diagram for bus dominant to RXD LOW.



The waveforms of the applied transients shall be in accordance with "ISO 7637 part 1", test pulses 1, 2, 3a and 3b.

Fig 8. Test circuit for automotive transients.

■ BLOCK DIAGRAM

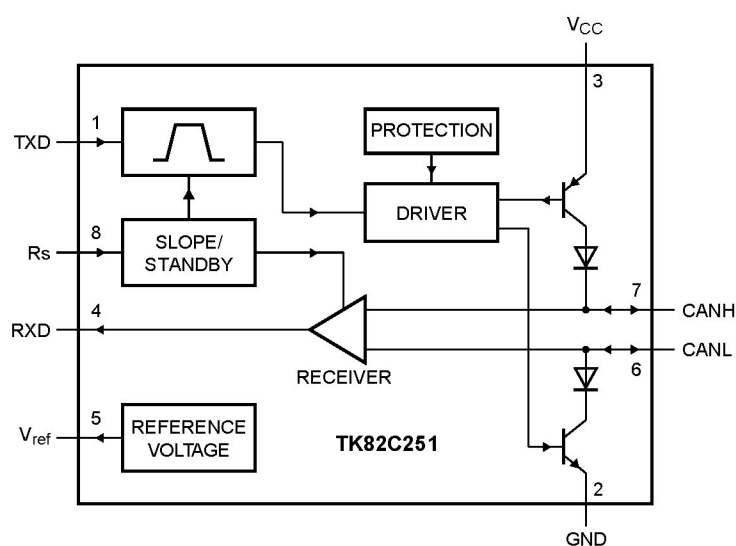
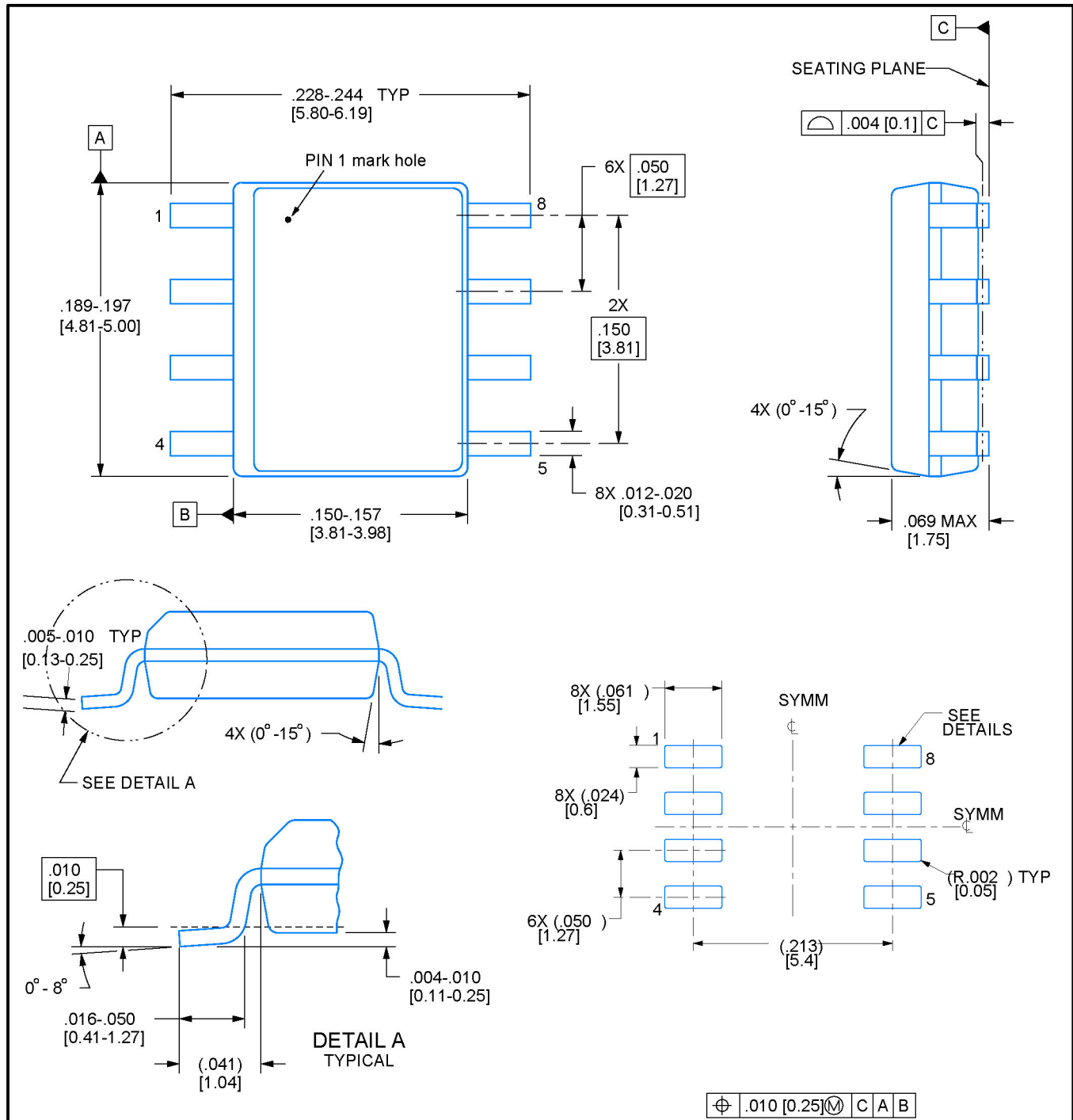


Fig 9. Block diagram

PACKAGE OUTLINE SOIC - 8,1.75 mm max height



NOTES: Linear dimensions are in inches [millimeters]. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.